

A mixed ultrasoft/normconserved pseudopotential scheme

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Abstract

A variant of the Vanderbilt ultrasoft pseudopotential scheme, where the normconservation is released for only one or a few angular channels, is presented. Within this scheme some difficulties of the truly ultrasoft pseudopotentials are overcome without sacrificing the pseudopotential softness. i) Ghost states are easily avoided without including semicore shells. ii) The ultrasoft pseudo-charge-augmentation functions can be made more soft. iii) The number of nonlocal operators is reduced. The scheme will be most useful for transition metals, and the feasibility and accuracy of the scheme is demonstrated for the 4d transition metal rhodium.

With the development of the Vanderbilt Ultrasoft-pseudopotential (US) technique [1] it has become possible to describe traditionally hard pseudopotential elements like transition metals and first row elements with a modest plane-wave cutoff. However, for some elements it is difficult to avoid the appearance of so-called ghost states without including semicore states in the pseudopotential construction [2]. Furthermore, sometimes it is necessary to describe the US pseudo-augmentation charge with a higher cutoff than the pseudo-charge of the wave-function sum, and therefore so-called double-grid techniques have been developed [3]. Both these aspects significantly reduce the computational efficiency of the US scheme, and it is desirable to find a simple scheme to avoid these difficulties.

In this report I will present a variant of the US technique, where only the Normconservation(NC) is released for some of the angular channels. The benefit from this construction is that the semi-local potential of one of the chemical active channels may be taken as the local potential. This reduces the number of projectors in the US scheme and by choosing the semi-local potential of the least bound reference state as the local potential, the appearance of ghost states is effectively avoided. Furthermore, since with this construction there are less pseudo-charge-augmentation functions, I have found the pseudo-charge smoothening procedure of Ref. [3] to be more efficient. In the following I will briefly review the main features of the US scheme, and present the modifications in a mixed US/NC scheme. Finally, I will build a US/NC pseudopotential for Rh and compare the transferability and computational efficiency with that of a NC pseudopotential and an US pseudopotential with semicore shells.

In the US scheme the pseudo-wave-functions do not obey a NC condition and it is this feature which makes it possible to construct pseudopotentials with a modest plane-wave cutoff ($\leq 30\text{Ry}$) for traditionally hard pseudopotential elements. To make the pseudopotential retain the first order scattering properties of the all-electron potential, as is the case of the NC pseudopotentials, the pseudo-wave-functions have to obey a generalized eigenvalue equation, where the missing norm enters in the overlap matrix. Furthermore, the density cannot simply be constructed from the pseudo-wave-functions, an augmentation charge has to be added in order to retain the correct electro-static potential in the interstitial region. Given a set of occupied pseudo-wave-functions $\{\Phi_\alpha\}$, the augmentation charge is given by

$$\rho^{aug}(\mathbf{r}) = \sum_{\alpha,n,m} \langle \Phi_\alpha | \chi_n \rangle Q_{nm}(\mathbf{r}) \langle \chi_m | \Phi_\alpha \rangle, \quad (1)$$

$$Q_{nm}(\mathbf{r}) = \psi_n^*(\mathbf{r})\psi_m(\mathbf{r}) - \phi_n^*(\mathbf{r})\phi_m(\mathbf{r}), \quad (2)$$

where ψ_n are the reference all-electron atomic wave-functions, ϕ_n the corresponding reference atomic pseudo-wave-functions, and χ_m are projectors upon the reference atomic pseudo-wave-functions.

With this choice for the augmentation charge the total pseudo density does not only have the same norm as the all-electron density, as in the case of NC pseudopotentials, but is identical to the all-electron density in the case where the set of reference states inside each core form a complete basis for the all-electron wave-functions and the pseudo-wave-functions, i.e. $\Psi_\alpha = \sum_n a_n^\alpha \psi_n$ and $\Phi_\alpha = \sum_n b_n^\alpha \phi_n$. To see this observe that since the pseudo and all-electron wave-functions and their radial derivatives coincide at the core radius they must have the same expansion in the reference states, thus $a_n^\alpha = b_n^\alpha$ which implies that $\sum_\alpha |\Psi_\alpha|^2 = \sum_\alpha |\Phi_\alpha|^2 + \rho^{aug}$.

Therefore, in the US scheme not only the electro-static mono-pole of the core region is

correct, but also higher order poles are described rather accurately. Another feature of the US scheme is the possibility to include several reference states for each angular channel.

In the NC scheme it is common practise to take one of the semi-local potentials as the local potential and thereby reduce the number of semi-local channels that have to be described. Furthermore, by choosing the semi-local potential of the least bound reference state one can effectively avoid the appearance of ghost states [4,5] in a Kleinmann-Bylander [6] implementation. A similar choice for the local potential in the ultrasoft scheme would produce a very poor pseudopotential, since due to the missing norm of the corresponding pseudo-wave-function the local potential would only have the zero-order scattering properties of the all-electron potential. Instead the common practise is to construct a semi-local potential for the first angular channel which is not chemical active and use that for the local potential, for instance, for the transition metals the semi-local potential of the f -channel is usually used for the local potential. However, for most transition metals this will produce a local potential with bound states far below the s - and p -reference eigenstates, and the appearance of ghost states is therefore unavoidable [5]. A solution to this problem is to include s - and p -semicore shells in the pseudopotential construction, since these new reference eigenstates usually are below the bound states of the local potential the ghost-states will disappear. The inclusion of semicore shells has the benefit that the accuracy of the pseudopotential gets comparable to all-electron calculations [7], however, it also increases the computer time and memory requirements of the calculation substantially.

As an alternative I propose a mixed US/NC scheme, where the normconservation is only released for the hard channels, and the semi-local potential of one of the soft channels may thereby be taken as the local potential. For most transition metals the normconservation will only have to be released for the d -channel, and the semi-local potential of the p -channel can therefore be taken as the local potential, thereby avoiding the appearance of ghost-states. The pseudo-charge-augmentation functions Q_{nm} of Eq. (2) I now define as

$$Q_{nm}(\mathbf{r}) = \xi_n^*(\mathbf{r})\xi_m(\mathbf{r}) - \phi_n^*(\mathbf{r})\phi_m(\mathbf{r}), \quad (3)$$

where $\xi = \psi$ for the US channels and $\xi = \phi$ for the NC channels, and only contributions from nonlocal channels are included, i.e. for most transition metals only the Q_{dd} and Q_{sd} elements will contribute to the augmentation charge.

In the following I will construct a scalar-relativistic mixed US/NC pseudopotential for the 4d transition metal Rh, show that the error introduced by the choice for the augmentation charge is minute, and compare the transferability and computational efficiency with a NC pseudopotential and a US pseudopotential with semicore states.

To construct the NC pseudopotential (denoted NC(9)) I used the procedure suggested by Troullier-Martins [8], with core radii 2.53, 2.53 and 1.39 (a.u.) for the s -, p - and d -channel, respectively. As suggested in Ref. [9], only the semi-local s - and d -potentials were constructed in the atomic ground-state configuration $4d^8 5s^1$, while the semi-local p -potential was constructed in the $4d^7 5s^{0.75} p^{0.25}$ configuration. Figure 1 shows the pseudo wave-functions and their Fourier transforms. From the latter it can be seen that the s - and p -wave-functions are converged at $\approx 20 - 25$ Ry, while the d -wave-function must be described with a cutoff of $\approx 50 - 60$ Ry. From this pseudopotential the mixed US/NC pseudopotential (denoted US/NC(9)) was constructed by releasing the norm of the d -wave-function, increasing its core radius to 1.6 a.u., and then using the smoothening procedure

of Ref. [10,7] to generate d -ultra-soft pseudo-wave-functions for two reference states, where one has the atomic eigenvalue (-0.4518 Ry) and the other the energy (0.2 Ry). With this construction the d -pseudo-wave-function can be described with a cutoff of $\approx 25 - 30$ Ry, as seen from its Fourier transform shown in Fig. 1b(dotted line). Finally, I have constructed an US pseudopotential including 4s and 4p semicore shells (denoted US(17)), using 2 reference states for each channel, and a core-radius of 2.0, 2.0 and 1.6 for the s -, p -, and d -channel, respectively. The US(17) pseudopotential is also converged at $\approx 25 - 30$ Ry.

To generate pseudo-charge-augmentation functions I have used the procedure described in Ref. [3,7], where the augmentation functions are replaced by L-dependent counterparts Q_{nm}^L ,

$$Q_{nm}(\mathbf{r}) = \sum_{LM} c_{LM}^{nm} Y_{LM}(\hat{r}) Q_{nm}^L(r), \quad (4)$$

which are smoothened inside a core radius, r_{in}^L , subject to the condition that the Lth moment of the electron charge density is conserved. One difficulty with this method is that if the core radius r_{in}^0 is extended beyond a certain radius the smoothening procedure starts to develop negative sections in the $Q_{nm}^0(r)$ terms, leading to negative pseudo-charge densities. I have found that this difficulty is related to the different node structure of the radial all-electron wave functions, and that a larger r_{in}^0 core radius can be chosen when there is only one angular channel. Figure 2 shows the Q_{ss}^0 , Q_{pp}^0 and Q_{dd}^0 pseudo-charge-augmentation functions of the US(17) pseudopotential and the Q_{dd}^0 pseudo-charge-augmentation function of the US/NC(9) pseudopotential. For the US(17) pseudopotential the core radius could not be extended beyond $r_{in}^0 = 0.6$ a.u., while the US/NC(9) core radius was $r_{in}^0 = 0.9$ a.u. giving softer pseudo-charge-augmentation functions.

Table 1 shows the transferability of the US/NC(9), NC(9) and US(17) pseudopotentials for atomic, bulk and surface properties of Rh. First notice the very high quality of the US(17) pseudopotential, having an accuracy essentially identical to all-electron calculations. Notice also the discrepancy (due to the local-density approximation) between the all-electron calculation and the experimental results for the bulk properties of Rh, which warns that the quality of a pseudopotential should never be judged by comparison with experimental data. The atomic calculations show that the main difference between the NC(9) and the US/NC(9) pseudopotentials, is the latter's enhanced description of the d -electrons, which is due to the use of two reference states.

Table 1c shows the CPU time used to obtain the self-consistent charge density of the non-relaxed surface for the three different pseudopotential schemes. The comparison reveals that the US/NC(9) pseudopotential is 3.8 times faster than the US(17) pseudopotential and 3.4 times faster than the NC(9) pseudopotential. For large systems the orthogonalization step is the most time-consuming part of a plane-wave program, and this scales as $O(NM^2)$, where N is the number of plane-waves and M the number of occupied bands. In the present case this gives a time factor relative to the US/NC(9) pseudopotential of $(17/9)^2 \approx 3.6$ for the US(17) pseudopotential and $2^{\frac{3}{2}} \approx 2.8$ for the NC(9) pseudopotential. Another important issue is the memory requirement which scales as $O(NM)$, which results in a factor $17/9 \approx 1.9$ for the US(9) pseudopotential and a factor $2^{\frac{3}{2}} \approx 2.8$ for the NC(9) pseudopotential relative to the US/NC(9) pseudopotential.

To test whatever the neglect of the Q_{pd} pseudo-charge-augmentation functions in the US/NC scheme introduce any significant error, I have constructed a US(17)* pseudopotential-

tial with $Q_{sp} = Q_{pd} = Q_{sd} = 0$. These terms are most important for asymmetric systems, however, the calculated Rh(110) surface properties are almost unaffected by this approximation (see Table 1c). Furthermore, I have found that different variations of the US/NC scheme as including two s -reference states, using the atomic ground state for the p -reference configuration or including the Q_{ss} term, do not change the quality of the pseudopotential significantly. The discrepancy between the US(17) and US/NC(9) pseudopotentials is therefore mainly due to the latter's neglect of semicore states.

In conclusion I have presented a simple scheme for constructing a mixed normconserved/ultrasoft pseudopotential using as a starting point a normconserved pseudopotential. The resulting pseudopotential scheme is more accurate and computationally efficient than the initial normconserved pseudopotential. Compared to truly ultrasoft schemes, ghost states are avoided without including semicore shells and the ultrasoft pseudo-augmentation charge is more easily described with the same cutoff as the wave-function pseudo-charge.

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FIGURES

FIG. 1. a) The real-space all-electron wave-functions of Rh and the pseudo-wave-functions of the NC(9) and US/NC(9) pseudopotentials. b) The Fourier-transformed pseudo-wave-functions.

FIG. 2. The Fourier-transformed pseudo-charge-augmentation functions of the US(17) and the US/NC(9) pseudopotential.

TABLES

TABLE I. Comparison of the three rhodium pseudopotentials. US(17) is the ultrasoft pseudopotential including semicore shells, NC(9) is the normconserved pseudopotential and US/NC(9) is the mixed normconserved/ultrasoft scheme. In all the calculations, including the atomic calculations of part a), the pseudopotentials are used in a non-local separable form. a) The calculated atomic-eigenvalues in different reference configurations and their deviation from the all-electron values. b) The lattice constant (a_0), bulk modulus (B), derivative of the bulk modulus (B'), and cohesive energy of rhodium. c) The surface energy (E_{surf}), workfunction(W), and interlayer relaxation (Δ_{12}, Δ_{23}) of the Rh(110) surface. The US(17)* pseudopotential neglects pseudo-charge-augmentation functions which couple different angular channels, i.e. $Q_{sp} = Q_{pd} = Q_{sd} = 0$.

a) Atomic properties of Rh							
pseudo	configuration	4d [Ry]	$\Delta(4d)$ [mRy]	5s [Ry]	$\Delta(5s)$ [mRy]	5p [Ry]	$\Delta(5p)$ [mRy]
US(17)	$4d^9 5s^0 5p^0$	-0.28267	0.0	-0.26864	0.0	-0.03501	0.0
US/NC(9)	$4d^9 5s^0 5p^0$	-0.28155	1.2	-0.27227	-3.6	-0.03798	-3.0
NC(9)	$4d^9 5s^0 5p^0$	-0.27479	7.9	-0.27022	-1.6	-0.03883	-3.8
US(17)	$4d^7 5s^1 5p^0$	-1.24280	0.1	-0.91783	0.0	-0.53999	0.1
US/NC(9)	$4d^7 5s^1 5p^0$	-1.24384	-0.9	-0.91472	3.1	-0.53760	2.5
NC(9)	$4d^7 5s^1 5p^0$	-1.25787	-15.0	-0.91985	-2.0	-0.53800	2.1
b) Bulk properties of Rh							
pseudo	cutoff [Ry]	a_0 [Å]	B [Mbar]	B'	E_{coh} [Ry/atom]		
Exp.		3.80 ^a	2.76 ^a		0.42 ^a		
All El.		3.74 ^b	3.46 ^b	7.3 ^b	0.569 ^b		
US(17)	30	3.75	3.44	7.8	0.636		
US/NC(9)	30	3.81	3.16	5.6	0.609		
NC(9)	60	3.86	2.98	5.5	0.594		
c) Surface properties of Rh(110)							
pseudo	Cutoff [Ry]	CPU time [s]	E_{surf} [eV/atom]	W [eV]	Δd_{12} [%]	Δd_{23} [%]	
Exp.				4.98 ^c	-6.9 ^d	1.9 ^d	
US(17)	30	5796	1.73	4.77	-12.1	4.9	
US/NC(9)	30	1514	1.92	4.99	-10.2	2.5	
NC(9)	60	5162	1.87	4.98	-10.5	2.6	
US(17)*	30	5796	1.73	4.78	-12.1	4.9	

^aReference [11] ^bReference [12] ^cReference [15](polycrystalline) ^dReference [14]



